## Supporting Information (SI): Tunable Electronic Properties of the Dynamically Stable Layered Mineral Pt<sub>2</sub>HgSe<sub>3</sub> (Jacutingaite)

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*Figure S1:* Strain-dependent electronic band dispersions of monolayer Pt<sub>2</sub>HgSe<sub>3</sub> under (a) uniaxial-tensile, (b) uniaxial-compressive, (c) biaxial-tensile, and (d) biaxial-compressive strains.